



















LMH9226

JAJSIA6 - DECEMBER 2019

LMH9226 シングルエンド、差動 2.3GHz~2.9GHz RF アンプ、バラン付 き

1 特長

- シングル・チャネル、シングルエンド入力から差 動出力への RF ゲイン・ブロック・アンプ
- 2.6GHz の中心周波数、400MHz の 1dB 帯域幅を サポート
- Z_{LOAD} = 50 Ω に対して 1dB 帯域幅全体で 17dB (標準値) のゲイン
- 1dB 帯域幅で 3dB 未満のノイズ指数
- $Z_{LOAD} = 50\Omega$ に対して 2dBm の 2 トーン出力電力 で 35dBm の OIP3
- Z_{I OAD} = 50Ω に対して 17.5dBm の出力 P1dB
- 3.3V 単一電源で 275mW の消費電力
- 最高 T_A = 105℃の動作温度

2 アプリケーション

- 5G m-MIMO 基地局
- アクティブ・アンテナ・システム (AAS) の mMIMO (マッシブ MIMO)
- スモール・セル基地局
- TDD/FDD セルラー基地局
- ワイヤレス・インフラ
- 低コスト無線
- シングルエンドから差動への変換
- バランの代替品
- RF ゲイン・ブロック
- GSPS ADC の差動ドライバ

3 概要

LMH9226 は、シングルエンド 50Ω 入力から差動 50Ω ま たは 100Ω 出力への高性能シングル・チャネル RF ゲイ ン・ブロック・アンプであり、2.3GHz~2.9GHz の周波数帯 に対応しています。このデバイスは、5G m-MIMO または スモール・セル基地局アプリケーションの要件を満たすの に最適です。本デバイスは、パッシブ・バランを接続したシ ングルエンド入力差動出力 RF ゲイン・ブロック機能を統 合しており、レシーバ信号チェーンの最終段でアナログ/ デジタル・コンバータ (ADC) の差動入力のフルスケール 電圧を駆動するために主に使用されます。

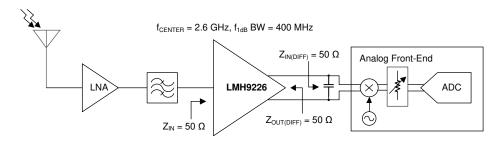
LMH9226 は、2.6GHz において 17dB (標準値) のゲイ ンと 35dBm の出力 IP3 という優れた線形性能を備えて おり、400MHz の 1dB 帯域幅全体にわたって 3dB 未満 のノイズ指数を維持します。このデバイスは、シングルエン ド入力で 50Ω のインピーダンスと内部的に整合します。 差動出力は、外部整合回路を使わずに 50Ω のインピー ダンスと簡単に接続できます。100Ω のインピーダンスに 整合させるには、2.6GHz で通常 0.3dB のゲイン損失を もたらす外部整合回路が必要です。

製品情報⁽¹⁾

型番	パッケージ	本体サイズ(公称)
LMH9226	WQFN(12)	2.00mm × 2.00mm

(1) 利用可能なすべてのパッケージについては、このデータシートの末 尾にある注文情報を参照してください。

LMH9226: 2.3GHz~2.9GHz シングルエンド入力差動出力 RF ゲイン・ブロック・アンプ







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4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

日付	リビジョン	注
2019年12月	*	初版



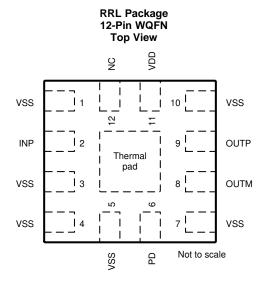
5 概要(続き)

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このデバイスは、3.3V 単一電源で動作させた場合、スタンバイ電力が約 275mW に過ぎないため、高密度、5G、マッシブ・マルチ入力 / マルチ出力 (MIMO) アプリケーションに適しています。このデバイスは省スペースの 2mm x 2mm、12 ピンの WQFN パッケージで供給されます。このデバイスは最高 105℃の動作温度で定格が規定されているため、堅牢なシステム設計が可能です。1.8V JEDEC 準拠のパワーダウン・ピンを利用すると、時分割多重化 (TDD) システムに適した高速なデバイスの電源オン / オフが可能です。



6 Pin Configuration and Functions



Pin Functions

PIN		1/0	DESCRIPTION
NO.	NAME	1/0	DESCRIPTION
1	VSS	Power	Analog ground
2	INP	Input	RF single-ended input into amplifier
3	VSS	Power	Analog ground
4	VSS	Power	Analog ground
5	VSS	Power	Analog ground
6	PD	Input	Power-down connection. PD = 0 V, normal operation; PD = 1.8 V, power off mode.
7	VSS	Power	Analog ground
8	OUTM	Output	RF single-ended output negative
9	OUTP	Output	RF single-ended output positive
10	VSS	Power	Analog ground
11	VDD	Power	Positive supply voltage (3.3 V)
12	NC	_	Do not connect this pin
Thermal Pad		_	Connect the thermal pad to ground (VSS).

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Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Supply voltage	VDD	-0.3	3.6	V
RF pins	INP, OUTP, OUTM	-0.3	VDD	V
Continuous wave (CW) input	f _{in} = 2.6 GHz at INP		25	dBm
Digital input pin	PD	-0.3	VDD	V
Junction temperature	TJ		150	°C
Storage temperature	T _{stg}	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
.,	Cleatrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, allpins ⁽¹⁾	±1000	.,
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specificationJESD22-C101, all pins (2)	±500	V

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
VDD	Supply voltage	3.15	3.3	3.45	V
T _A	Ambient temperature	-40		105	°C
TJ	Junction temperature	-40		125	°C

7.4 Thermal Information

		LMH9226	
	THERMAL METRIC ⁽¹⁾	RRL PKG	UNIT
		12-PIN WQFN	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	74.8	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	72.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	37.1	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	3.2	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	37.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	14.2	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.5 Electrical Characteristics

 $T_{A} = +25^{\circ}\text{C}, \text{ VDD} = 3.3 \text{ V}, \text{ center frequency } (f_{in}) = 2.6 \text{ GHz}, \text{ single-ended input impedance } (Z_{IN}) = 50 \text{ } \Omega, \text{ differential output impedance } (Z_{LOAD}) = 50 \text{ } \Omega, \text{ P}_{OUT(TOTAL)} = 8 \text{ dBm into } Z_{LOAD} = 50 \text{ } \Omega \text{ (unless otherwise noted)}$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
RF PERI	FORMANCE					
f _{RF}	RF frequency range		2300		2900	MHz
BW _{1dB}	1-dB bandwidth	Center Frequency (f _{in}) = 2.6 GHz		400		MHz
S21	Gain	f _{in} = 2.6 GHz		17		dB
NF	Noise figure	f_{in} = 2.6 GHz, R_S = 50 Ω		3		dB
OIP1	Output P1dB	f_{in} = 2.6 GHz, R_{LOAD} = 50 Ω		17.5		dBm
OIP3	Output IP3	f _{in} = 2.6 GHz ± 10 MHz spacing, P _{OUT/TONE} = 2 dBm		35		dBm
	Differential output gain imbalance (1)			0.5		dB
	Differential output phase imbalance (1)			4		degree
S11	Input return loss	f _{in} = 2.6 GHz, BW = 400 MHz		-11		dB
Z _{IN}	Single ended input reference impedance			50		Ω
S22	Differential output return loss	f _{in} = 2.6 GHz, BW = 400 MHz		-12		dB
Z _{LOAD}	Differential ouput reference impedance			50		Ω
S12	Reverse isolation	f _{in} = 2.6 GHz		-35		dB
CMRR	Common-mode rejection ratio (2)			27		dB
SWITCH	ING AND DIGITAL INPUT CHARACTERIS	TICS	•			
t _{ON}	Turn-on time	PD pin = 1.8 V to 0 V, f _{in} = 2.6 GHz		0.5		μs
t _{OFF}	Turn-off time	PD pin = 0 V to 1.8 V, f _{in} = 2.6 GHz		0.2		μs
V _{IH}	High-level input voltage (3)	At the PD pin	1.4			V
V _{IL}	Low-level input voltage (3)	At the PD pin			0.5	V
I _{IH}	High-level input current (3)	At the PD pin		28	60	μΑ
I _{IL}	Low-level input current (3)	At the PD pin		10	30	μΑ
DC CUR	RENT AND POWER CONSUMPTION					
I _{VDD_ON}	Supply current (3)	PD pin = 0 V		84	100	mA
I _{VDD_PD}	Power-down current (3)	PD pin = 1.8 V			10	mA
P _{dis}	Power dissipation	VDD = 3.3 V		275		mW

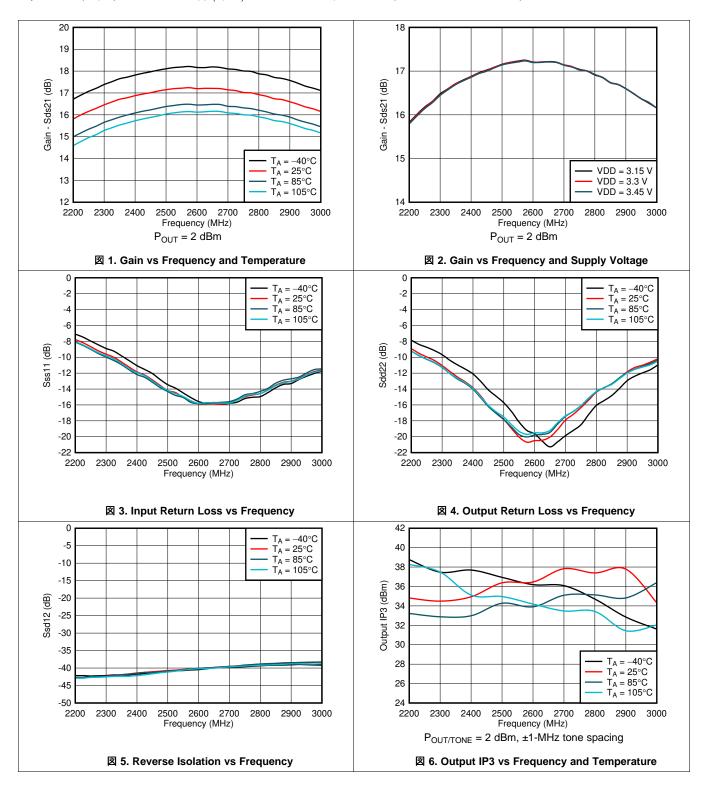
Measured at f_{in} = 2.6GHz, over the BW_{1dB} CMRR is calculated using (S21-S31)/(S21+S31) for receive (1 is input port, 2 and 3 are differential output ports) 100% tested at T_A = 25°C



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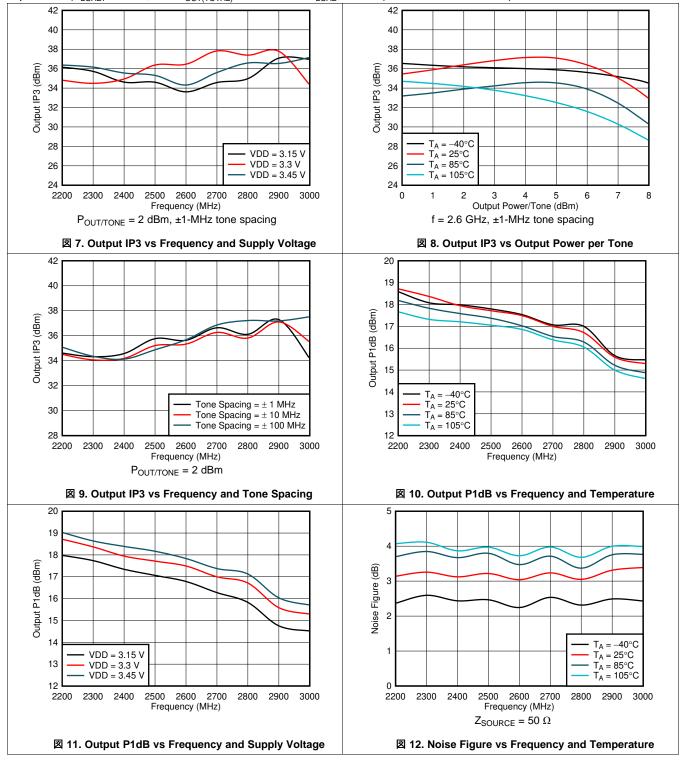
7.6 Typical Characteristics

at T_A = 25°C, VDD = 3.3 V, center frequency (f_{IN}) = 2.6 GHz, single-ended input impedance (Z_{IN}) = 50 Ω , differential output impedance (Z_{LOAD}) = 50 Ω , and $P_{OUT(TOTAL)}$ = 8 dBm into Z_{LOAD} = 50 Ω (unless otherwise noted)



Typical Characteristics (continued)

at T_A = 25°C, VDD = 3.3 V, center frequency (f_{IN}) = 2.6 GHz, single-ended input impedance (Z_{IN}) = 50 Ω , differential output impedance (Z_{LOAD}) = 50 Ω , and $P_{OUT(TOTAL)}$ = 8 dBm into Z_{LOAD} = 50 Ω (unless otherwise noted)

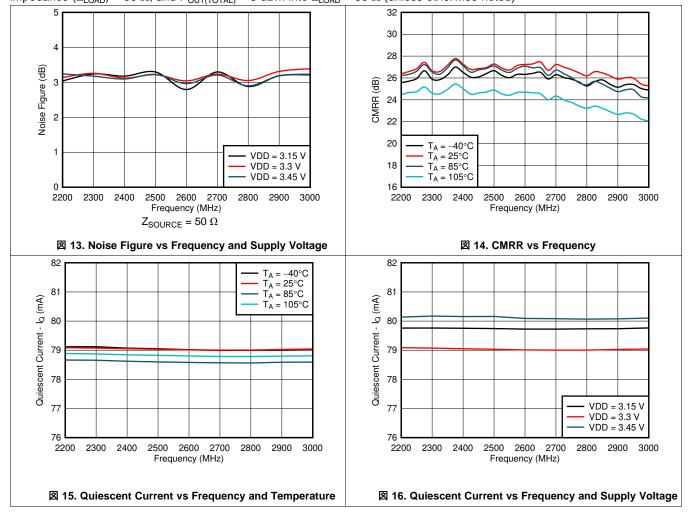




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Typical Characteristics (continued)

at T_A = 25°C, VDD = 3.3 V, center frequency (f_{IN}) = 2.6 GHz, single-ended input impedance (Z_{IN}) = 50 Ω , differential output impedance (Z_{LOAD}) = 50 Ω , and $P_{OUT(TOTAL)}$ = 8 dBm into Z_{LOAD} = 50 Ω (unless otherwise noted)



8 Detailed Description

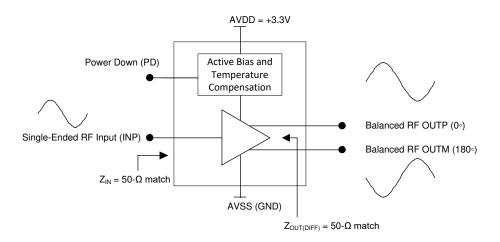
8.1 Overview

The LMH9226 is single-ended, $50-\Omega$ input to differential $50-\Omega$ or $100-\Omega$ output RF gain block amplifier used in 2.3-GHz to 2.9-GHz, frequency-band, 5G, m-MIMO TDD receiver applications. The device provides a 17-dB fixed power gain with excellent linearity and noise performance across 400 MHz of the 1-dB bandwidth at the 2.6-GHz center frequency. The device is internally matched for a $50-\Omega$ input impedance at 2.6 GHz. The device differential output can be matched to the $50-\Omega$ impedance without external matching circuitry, or to the $100-\Omega$ impedance with external matching circuitry (see the *Application and Implementation* section for details). The device is typically used in the final stage of a receive signal chain to drive the differential input of an analog-to-differential converter (ADC), while providing additional gain to a low-noise amplifier (LNA) to increase dynamic range and the required single-ended to differential conversion.

The LMH9226 has an on-chip active bias circuitry to maintain device performance over a wide temperature and supply voltage range. The included power-down function allows the amplifier to shut down and save power when the amplifier is not needed. Fast shut-down and start-up enable the amplifier to be used in a host of time division duplex (TDD) applications.

Operating on a single 3.3-V supply and consuming 84 mA of typical supply current, the device is available in a 2-mm x 2-mm, 12-pin WQFN package.

8.2 Functional Block Diagram



8.3 Feature Description

As shown in 217, the LMH9226 integrates the functionality of a single-ended RF amplifier and passive balun in a traditional receive application, achieving a small form factor with good linearity and noise performance. The active balun implementation, along with a higher operating temperature of 105°C, allows for a more robust receiver system implementation compared to a passive balun that is prone to reliability failures at high temperatures. The high-temperature operation is achieved by the on-chip, active bias circuitry that maintains device performance over a wide temperature and supply voltage range.

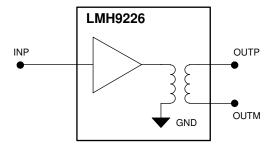


図 17. Single-Ended Input to Differential Output, Active Balun Implementation



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8.4 Device Functional Modes

The LMH9226 features a PD pin that must be connected to GND for normal operation. For power-down mode, connect the PD pin to a logic high voltage of 1.8 V.

9 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The LMH9226 is a single-ended, $50-\Omega$ input to differential $50-\Omega$ or $100-\Omega$ output RF gain block amplifier, used in the receive path of a 2.6-GHz center frequency, 5G, TDD m-MIMO or small cell base station. The device replaces the traditional single-ended RF amplifier and passive balun offering a smaller footprint solution to the customer. TI recommends following good RF layout and grounding techniques to maximize the device performance.

9.2 Typical Application

The LMH9226 is typically used in a four transmit and four receive (4T/4R) array of active antenna system for 5G, TDD, wireless base station applications. Such a system is shown in 2 18, where the LMH9226 is used in the receive path as the final stage differential driver to an ADC input. TI typically recommends reducing the trace distance between the LMH9226 output and the ADC input to minimize amplitude and phase imbalance during the single-to-differential conversion.

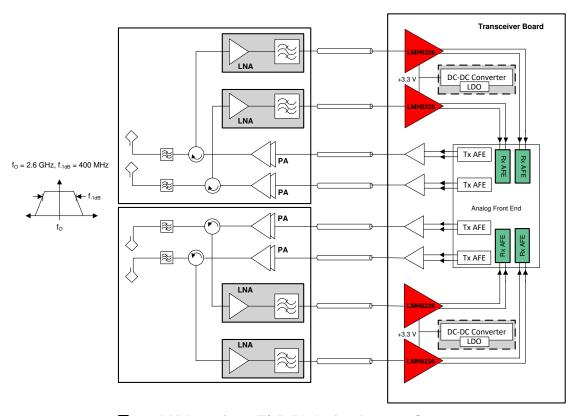


図 18. LMH9226 in a 4T/4R 5G Active Antenna System

Typical Application (continued)

The 4T/4R system is easily scaled to 16T/16R, 64T/64R, or higher antenna arrays that result in proportional scaling of the overall system power dissipation. As a result of the proportional scaling factor for multiple channels in a system, the individual device power consumption must be reduced to dissipate less overall heat in the system. Operating on a single 3.3-V supply, the LMH9226 consumes only 275 mW and therefore provides power saving to the customer. Multiple LMH9226 devices can be powered from a single DC/DC converter or a low-dropout regulator (LDO) operating on a 3.3-V supply. A DC/DC converter provides the most power efficient way of generating the 3.3-V supply. However, care must be taken when using the DC/DC converter to minimize the switching noise using inductor chokes and adequate isolation must be provided between the analog and digital supplies.

9.2.1 Design Requirements

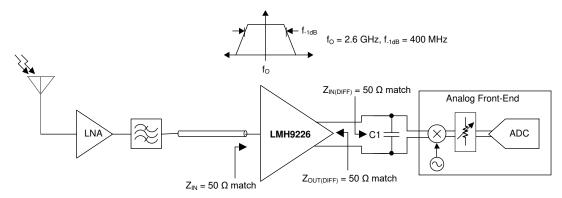
表 1 shows example design requirements for an RF amplifier in a typical 5G, active antenna TDD system. The LMH9226 meets these requirements.

DESIGN PARAMETERS	EXAMPLE VALUE			
Frequency range and 1-dB BW	2300 MHz to 2900 MHz with 400 MHz of 1-dB BW			
Configuration	Single-ended 50- Ω input to differential 50- Ω output			
Power gain	> 15 dB			
Output IP3 at P _{OUT/TONE} = 2 dBm	> 32 dBm			
Noise figure at Zin = 50 Ω	< 4 dB			
Output P1dB	< 17 dBm			
Power consumption	< 350 mW			
Turn-on time	< 1 µs			
Package size	2 mm × 2 mm ²			

表 1. Design Parameters

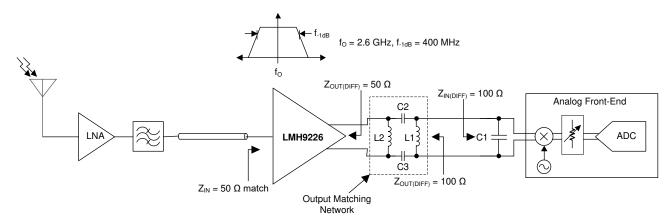
9.2.2 Detailed Design Procedure

The LMH9226 is a single-to-differential RF gain block amplifier for a 2.6-GHz center frequency application with 400 MHz of the 1-dB bandwidth. \boxtimes 19 shows a single receive channel consisting of a low-noise amplifier (LNA) that sits close to the antenna and drives the signal into a single-ended, 50- Ω coaxial cable that then connects to a transceiver board. The LMH9226 that sits at the transceiver board input converts this single-ended signal received from the coax cable into a differential signal, thereby offering low noise and distortion performance while interfacing with the receiver analog front-end (AFE). The LMH9226 input impedance must be matched to 50 Ω to prevent any signal reflections resulting from the coax cable. The device differential output interfaces directly with the differential input of an AFE. The output matching is optimized for a 50- Ω output at the 2.6-GHz center frequency with 400 MHz of the 1-dB bandwidth. The AFE input impedance must be matched to 50 Ω at 2.6 GHz as well to prevent any ripple in the frequency response.



2 19. LMH9226 in a Receive Application Driving an AFE ($Z_{OUT(DIFF)} = 50 Ω$)



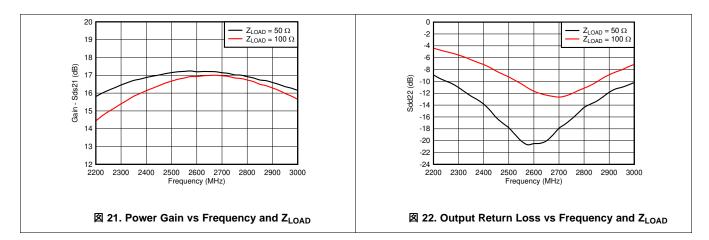


20. LMH9226 in a Receive Application Driving an AFE ($Z_{OUT(DIFF)} = 100 \Omega$)

COMPONENT	VALUE
C2, C3	2.2 pF
L1	6.2 nH
L2	Do not install (DNI)

Following the recommended RF layout with good quality RF components and local DC bypass capacitors ensures optimal performance is achieved. TI provides various support materials including S-parameter and ADS models to allow the design to be optimized to the application-specific performance needs.

9.2.3 Application Curves



10 Power Supply Recommendations

The LMH9226 operates on a common nominal 3.3-V supply voltage. The supply voltage is recommended to be isolated through the decoupling capacitors placed close to the device. Select capacitors with a self-resonant frequency near the application frequency. When multiple capacitors are used in parallel to create a broadband decoupling network, place the capacitor with the higher self-resonant frequency closer to the device.

The LMH9226 can be powered from a DC/DC converter or an LDO operating on a 3.3-V supply. A DC/DC converter provides the most power efficient way of generating the 3.3-V supply. However, care must be taken when using the DC/DC converter to minimize the switching noise from inductor chokes and adequate isolation must be provided between the analog and digital supplies.



11 Layout

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11.1 Layout Guidelines

When dealing with an RF amplifier with relatively high gain and a center frequency of 2.6 GHz, certain board layout precautions must be taken to ensure stability and optimum performance. TI recommends that the LMH9226 board be multi-layered to improve thermal performance, grounding, and power-supply decoupling.

23 shows a good layout example. In

23, only the top signal layer and its adjacent ground reference plane are shown.

- Excellent electrical connection from the thermal pad to the board ground is essential. Use the recommended
 footprint, solder the pad to the board, and do not include a solder mask under the pad.
- Connect the pad ground to the device terminal ground on the top board layer.
- Verify that the return DC and RF current path have a low impedance ground plane directly under the package and that the RF signal traces into and out of the amplifier.
- Ensure that ground planes on the top and any internal layers are well stitched with vias.
- Do not route RF signal lines over breaks in the reference ground plane.
- Avoid routing clocks and digital control lines near RF signal lines.
- Do not route RF or DC signal lines over noisy power planes. Ground is the best reference, although clean power planes can serve where necessary.
- Place supply decoupling close to the device.
- The differential output traces must be symmetrical in order to achieve the best linearity performance.

A board layout software package can simplify the trace thickness design to maintain impedances for controlled impedance signals. To isolate the affect of board parasitic on frequency response, TI recommends placing the external output matching resistors close to the amplifier output pins. See the *LMH9226 Evaluation Module* user guide for more details on board layout and design.

11.2 Layout Example

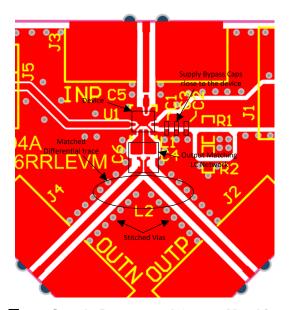


図 23. Supply Bypass and Output Matching

12 デバイスおよびドキュメントのサポート

12.1 ドキュメントのサポート

12.1.1 関連資料

関連資料については、以下を参照してください。

テキサス・インスツルメンツ『LMH9226 Evaluation Module』ユーザー・ガイド (英語)

12.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.comのデバイス製品フォルダを開いてください。右上の「アラートを受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

12.3 コミュニティ・リソース

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.4 商標

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.5 静電気放電に関する注意事項



すべての集積回路は、適切なESD保護方法を用いて、取扱いと保存を行うようにして下さい。

静電気放電はわずかな性能の低下から完全なデバイスの故障に至るまで、様々な損傷を与えます。高精度の集積回路は、損傷に対して敏感であり、極めてわずかなパラメータの変化により、デバイスに規定された仕様に適合しなくなる場合があります。

12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 メカニカル、パッケージ、および注文情報

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www.ti.com 10-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
LMH9226IRRLR	Active	Production	WQFN (RRL) 12	3000 LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 105	22GO
LMH9226IRRLR.B	Active	Production	WQFN (RRL) 12	3000 LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 105	22GO

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

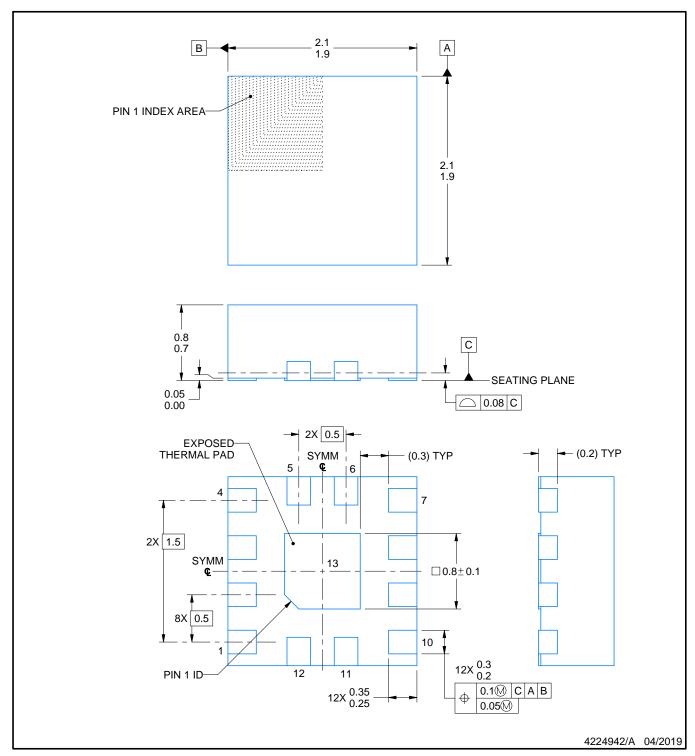
⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PLASTIC QUAD FLATPACK - NO LEAD

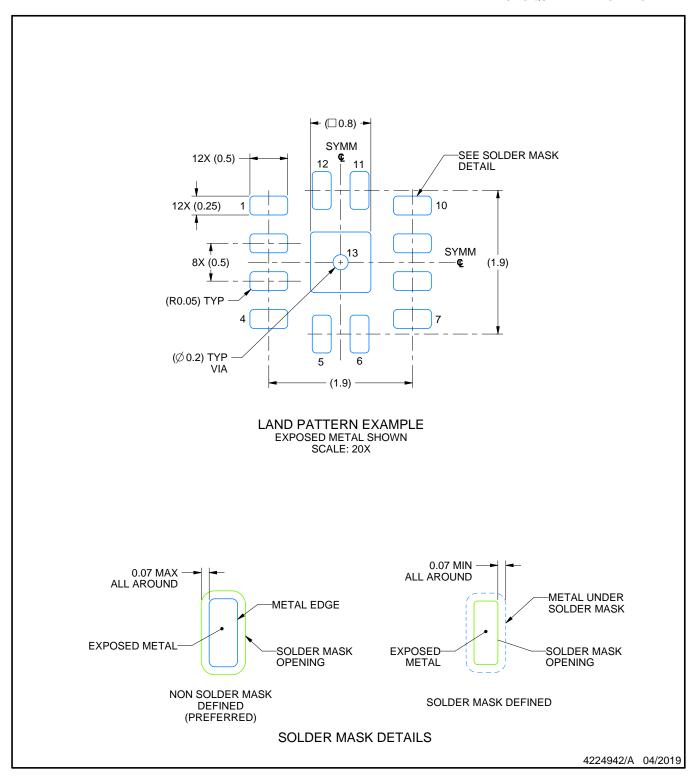


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

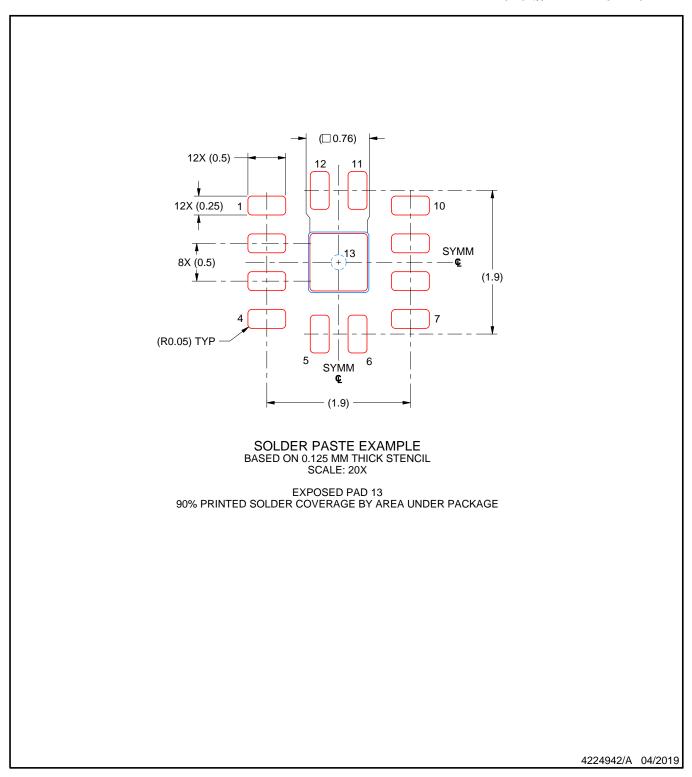


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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